

BTA04 T/D/S/A BTB04 T/D/S/A

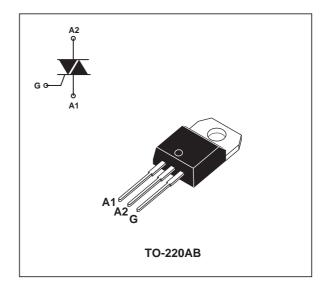
SENSITIVE GATE TRIACS

FEATURES

- Very low I_{GT} = 10mA max
- Low I_H = 15mA max
- BTA Family: Insulating voltage = 2500V_(RMS) (UL recognized: E81734)

DESCRIPTION

The BTA/BTB04 T/D/S/A triac family are high performance glass passivated PNPN devices. These parts are suitables for general purpose applications where gate high sensitivity is required. Application on 4Q such as phase control and static switching.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit		
I _{T(RMS)}	RMS on-state current (360° conduction angle)	BTA	$Tc = 90^{\circ}C$	4	Α
		BTB	$Tc = 95^{\circ}C$		
I _{TSM}	Non repetitive surge peak on-state current	state current tp = 8.3ms		42	A
	(Tj initial = 25°C)	$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	40		
l ² t	l ² t value		tp = 10ms	8	A ² s
dl/dt	dl/dt Critical rate of rise of on-state current Gate supply: $I_G = 50 \text{mA}$ $dI_G/dt = 0.1 \text{A}/\mu \text{s}$			10	A/µs
			Non repetitive	50	
Tstg Tj	Storage and operating junction temperature range			-40 to +150 -40 to +110	°C
TI	Maximum lead soldering temperature during 10s at	4.5mm f	rom case	260	°C

Symbol	Baramatar		11:0:14			
Symbol	Parameter	400 T/D/S/A	600 T/D/S/A	700 T/D/S/A	Unit	
V _{DRM} V _{RRM}	Repetitive peak off-state voltage Tj = 110°C	400	600	700	V	

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THERMAL RESISTANCE

Symbol	Parameter	Value	Unit	
Rth (j-a)	Junction to ambient		60	°C/W
Rth (j-c) DC	Junction to case for DC	BTA	4.4	°C/W
		BTB	3.2	
Rth (j-c) AC	Junction to case for 360° conduction angle (F = 50Hz)	BTA	3.3	°C/W
		BTB	2.4	

GATE CHARACTERISTICS (maximum values)

 $P_{G(AV)} = 1W$ $P_{GM} = 40W$ (tp = 20µs) $I_{GM} = 4A$ (tp = 20µs) $V_{GM} = 16V$ (tp = 20µs)

ELECTRICAL CHARACTERISTICS

	Test conditions				BTA / BTB04				
Symbol			Quadrant		т	D	S	Α	Unit
I _{GT}	$V_D = 12V (DC)$ $R_L = 33\Omega$	Tj = 25°C	- -	MAX.	5	5	10	10	mA
			IV	MAX.	5	10	10	25	
V _{GT}	$V_{D} = 12V (DC) R_{L} = 33\Omega$	Tj = 25°C	I - II - III - IV	MAX.		1	.5		V
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3 k\Omega$	Tj =110°C	I - II - III - IV	MIN.		0.2			V
tgt	$\label{eq:VD} \begin{array}{l} V_D = V_{DRM} I_G = 40 mA \\ dI_G/dt = 0.5 A/\mu s \end{array}$	Tj = 25°C	I - II - III - IV	TYP.	2			μs	
١L	$I_{G} = 1.2I_{GT}$	Tj = 25°C	I - III - IV	TYP.	10	10	20	20	mA
			II		20	20	40	40	
I _H *	I _T = 100mA Gate open	Tj = 25°C		MAX.	15	15	25	25	mA
V _{TM} *	$I_{TM} = 5.5A$ tp = 380µs	Tj = 25°C		MAX.	1.65		V		
I _{DRM}	V _{DRM} rated	Tj = 25°C		MAX.	0.01		mA		
I _{RRM}	RRM V _{RRM} rated			MAX.		0.	75		
dV/dt *	Linear slope up to	Tj = 110°C		TYP.	10	10	-	-	V/µs
	$V_D = 67\% V_{DRM}$ gate open			MIN.	-	-	10	10	
(dl/dt)c*	(dl/dt)c = 1.8A/ms	Tj = 110°C		TYP.	1	1	5	5	V/µs

* For either polarity of electrode A_2 voltage with reference to electrode A_1

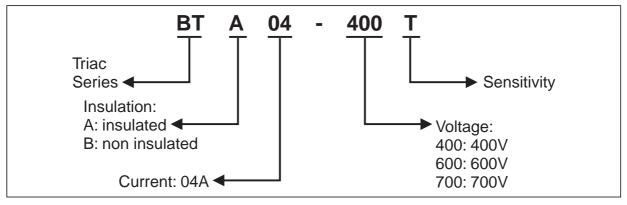
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PRODUCT INFORMATION

Deckere	I _{T(RMS)}	V _{DRM} / V _{RRM}	Sensitivity Specification				
Package	Α	v	т	D	S	Α	
BTA	4	400	Х			Х	
(Insulated)		600	Х	Х			
		700	Х		Х		
BTB		400	Х	Х			
(Uninsulated)		600	Х		Х		

ORDERING INFORMATION

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Fig. 1: Maximum RMS power dissipation versus RMS on-state current (F = 50Hz).(Curves are cut off by (dl/dt)c limitation)

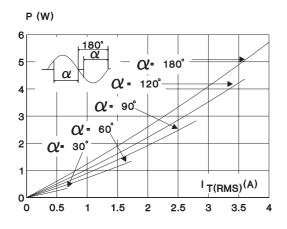


Fig. 3: Correlation between maximum RMS power dissipation and maximum allowable temperature (Tamb and Tcase) for different thermal resistances heatsink + contact (BTB).

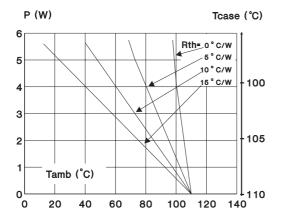


Fig. 5: Relative variation of thermal impedance versus pulse duration.

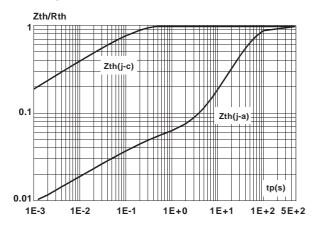


Fig. 2: Correlation between maximum RMS power dissipation and maximum allowable temperature (Tamb and Tcase) for different thermal resistances heatsink + contact (BTA).

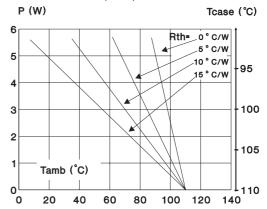


Fig. 4: RMS on-state current versus case temperature.

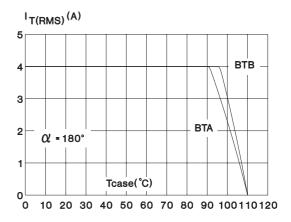
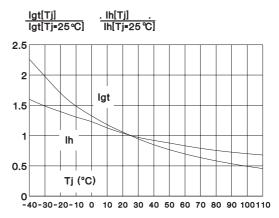


Fig. 6: Relative variation of gate trigger current and holding current versus junction temperature.



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Fig. 7: Non repetitive surge peak on-state current versus number of cycles.

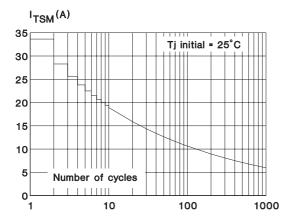


Fig. 9: On-state characteristics (maximum values).

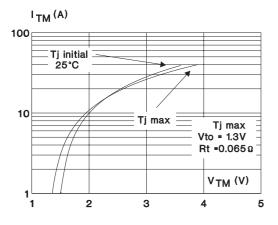
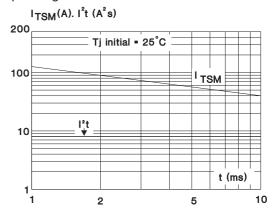


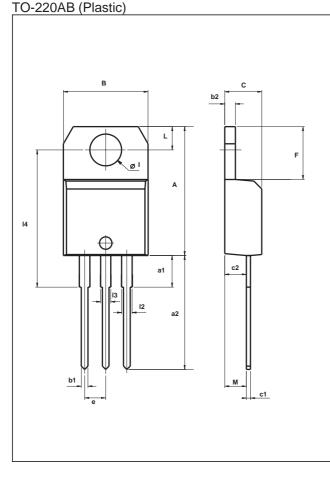
Fig. 8: Non repetitive surge peak on-state current for a sinusoidal pulse with width: $t \le 10$ ms, and corresponding value of l^2t .



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PACKAGE MECHANICAL DATA



	DIMENSIONS						
REF.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	15.20		15.90	0.598		0.625	
a1		3.75			0.147		
a2	13.00		14.00	0.511		0.551	
В	10.00		10.40	0.393		0.409	
b1	0.61		0.88	0.024		0.034	
b2	1.23		1.32	0.048		0.051	
С	4.40		4.60	0.173		0.181	
c1	0.49		0.70	0.019		0.027	
c2	2.40		2.72	0.094		0.107	
е	2.40		2.70	0.094		0.106	
F	6.20		6.60	0.244		0.259	
Ι	3.75		3.85	0.147		0.151	
14	15.80	16.40	16.80	0.622	0.646	0.661	
L	2.65		2.95	0.104		0.116	
12	1.14		1.70	0.044		0.066	
13	1.14		1.70	0.044		0.066	
Μ		2.60			0.102		

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OTHER INFORMATION

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
BTA/BTB04-xxxy	BTA/BTB04-xxxy	TO-220AB	2.3 g	250	Bulk

Epoxy meets UL94,V0

- Cooling method: C
- Recommended torque value: 0.8 m.N.
- Maximum torque value: 1 m.N.

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